Disturbing the dimers: Electron and hole doping in the intermetallic insulator FeGa₃

Antia S. Botana,* Yundi Quan, and Warren E. Pickett†

Department of Physics, University of California-Davis, Davis, California 95616, USA

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Insulating FeGa₃ poses peculiar puzzles beyond the occurrence of an electronic gap in an intermetallic compound. This Fe-based material has a very distinctive structural characteristic with the Fe atoms occurring in dimers. The insulating gap can be described comparatively well in either the weakly correlated limit or the strongly correlated limit within density functional theory viewpoints, where the latter corresponds to singlet formation on the Fe₂ dimers. Though most of the calculated occupied Wannier functions are admixtures of Fe 3d and Ga 4s or 4p states, there is a single bonding-type Wannier function per spin centered on each Fe₂ dimer. Density functional theory methods have been applied to follow the evolution of the magnetic properties and electronic spectrum with doping, where unusual behavior is observed experimentally. Both electron and hole doping are considered, by Ge and Zn on the Ga site, and by Co and Mn on the Fe site, the latter introducing direct disturbance of the Fe₂ dimer. Results from weakly and strongly correlated pictures are compared. Regardless of the method, magnetism including itinerant phases appears readily with doping. The correlated picture suggests that in the low doping limit Mn (for Fe) produces an in-gap hole state, while Co (for Fe) introduces a localized electronic gap state.

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I. BACKGROUND

FeGa₃ is a rare intermetallic insulator that has attracted particular attention due to its unusual transport and magnetic properties. This Fe-based material exhibits semiconducting behavior with a gap of 0.5 eV obtained from transport measurements [1]. Particular attention has been paid to understand the mechanism of the gap formation in the context of strong hybridization between Fe-3d and Ga-4p orbitals, reminiscent of that in strongly correlated 3d and 4f Kondo insulators [2].

Given the small band gap and the presence of very narrow bands around the Fermi level, FeGa₃ has been most extensively studied as a thermoelectric material. High values of the Seebeck coefficient around 350 μV/K have been measured at room temperature [3]. In single crystals colossal values of the thermopower (≈−16000μV/K) emerge below 20 K due to the phonon drag effect [4].

There is no unambiguous picture about the role of electronic correlations and the magnetic (or not) character of stoichiometric FeGa₃ from experiments. According to susceptibility measurements, FeGa₃ is diamagnetic below room temperature (RT) and the susceptibility shows an increase above RT suggesting proximity to a crossover to a paramagnetic metallic state [1]. Fe Mössbauer spectra did not show the presence of an internal magnetic field at the Fe site, supporting a nonmagnetic state of Fe [5] though not ruling out correlated states. In contrast, muon spin rotation studies detected spectroscopic features interpreted in terms of electron confinement into spin polarons that require the existence of Fe moments [6]. The narrow gap in FeGa₃ and its unusual properties suggesting electronic correlations brings to mind related iron compounds FeSi [7–9] and FeSb₂ [10,11], whose underlying electronic systems remain to be fully understood.

Hole or electron doping drastically changes the properties of the parent compound, giving rise to emergent magnetic phases. FeGa₃ has a very distinctive structural characteristic: Fe atoms occur in dimers as shown in Fig. 1. Replacing Fe breaks the dimer symmetry, a fundamental impact if there is important Fe-Fe bonding, spin correlations, or singlet formation. Focusing first on electron doping, Co substitution for Fe induces an insulator-to-metal transition [2,12,13]. Resistivity ρ(T) measurements for Fe₁₋ₓCoₓGa₃ are not yet conclusive; some indicate the metallic state is reached at doping level x = 0.025−0.075 [12], in other reports only at substantially higher doping levels of x = 0.125 [2] or 0.23 [13].

Analysis of the T dependence of the nuclear spin-lattice relaxation rate 1/T₁ of the ⁷⁹,⁷⁷Ga nuclei suggests the existence of in-gap states at low Co doping [12]. In Fe₀.₅Co₀.₅Ga₃, the relaxation is strongly enhanced due to spin fluctuations, often a signature of a weakly antiferromagnetic (AFM) metal. Such itinerant antiferromagnetic behavior contrasts with magnetization measurements, showing localized magnetism with a relatively low effective moment of 0.7 μₜ [12].

Electron doping by substituting Ga by Ge leads to drastically different behavior [13,14]. Experiments show that FeGaₓ₋ₙGeₓ is conducting at an extremely low doping level y = 0.0006, progressing to a weak ferromagnetic order at yₓ = 0.13 which never appears in the Co-doped compound. The emergence of the ferromagnetic (FM) state is accompanied by quantum critical behavior observed in the specific heat and the magnetic susceptibility. The FM instability found in FeGaₓ₋ₙGeₓ beyond yₓ = 0.13 indicates that strong electron correlations are induced by the disturbance of Fe 3d-Ga 4p hybridization, or possibly that existing strong correlations are disrupted [13].

Turning now to hole doping, Gamza et al. [15] performed resistivity and thermodynamic measurements on single crystals of Fe₃Ga₃, Fe₁₋ₓMnₓGa₃, and Fe₃Gaₓ₋ₙZnx (x ≲ 0.12 and y ≲ 0.06). Unlike for electron doping, hole doping using Mn on the Fe site or Zn on the Ga site does not give rise to a semiconductor-to-metal transition. Hole doping induces...
states into the semiconducting gap that remain localized at the highest doping levels. Using neutron powder diffraction measurements, they conclude that FeGa$_3$ orders magnetically above room temperature in a complex structure, unaffected by the inclusion of Mn and Zn.

Evidently input from theoretical modeling is required to move toward understanding of this unusual behavior. One emphasis of this paper is to give special attention to the metal dimers in this structure. The flat bands bordering the gap suggest correlated electron behavior, and interatomic correlations should be much stronger between electrons or spins within a dimer than between dimers, and local physics may appear. The situation can be illustrated by considering Fe$_{0.5}$Co$_{0.5}$Ga$_3$ mentioned above. Any given dimer has a 25% chance of being Fe$_2$, 25% chance of being Co$_2$, and 50% chance of FeCo. These three configurations may have very different physics, and their states may lie in the gap (and may destroy it) or in the sea of itinerant states. The system average may be very complex. Doping on the Ga site, however, does not directly disturb the dimers, and the change in band filling may be easier to handle and to understand.

DFT-based calculations for FeGa$_3$ have been reported using the two more common (semi)local approaches for the exchange correlation energy and potential: local density approximation (LDA) [16] and generalized gradient approximation (GGA) [17]. The very similar results seem to be sufficient for describing the electronic structure of the undoped compound, giving a value [18] of the gap of 0.4–0.5 eV comparable to the experiments. However, those approaches are unable to model the AFM phase in Co-doped FeGa$_3$, and they incorrectly predict a metallic FM ground state for hole doped FeGa$_3$, whether by Ga or Fe substitution. Within the correlated DFT LDA + $U$ method (see Sec. VI), local moments arise on the Fe dimer if the spins are antialigned, giving an antiferromagnetic result in band theory.

In view of these results, Yin and Pickett [18] suggested that the Fe dimers could be forming spin singlets—strongly correlated but nonmagnetic local states—and that magnetism found in doped FeGa$_3$ would be linked to the breaking of the singlets into free spins. Singh showed [19] that the magnetism of some types of doping of FeGa$_3$ can be explained within GGA without the need of spin coupling of pre-existing moments. This weakly correlated picture suggests that both $n$-type and $p$-type FeGa$_3$ will become itinerant ferromagnets [19] due to the large density of states on either side of the gap. Recently, it has been proposed from DFT-based calculations combined with Fe Mössbauer spectroscopy that increasing Ge-doping level ($y$) in FeGa$_{3-y}$Ge$_y$ over a wide range $0.3 \leq y \leq 0.5$ leads to an evolution from localized moments to a combination of localized and itinerant moments with the interplay of ferromagnetism and antiferromagnetism [20]. Dynamical mean field theory (DMFT) calculations have also been performed in FeGa$_3$ [15], showing that Fe ions are dominantly in an $S = 1$ state displaying strong spin and charge fluctuations. The DMFT approach is unable to model interatomic spin correlations.

The use of a nonmultiplicative (nonlocal) potential such as LDA + $U$ and the explanation in terms of an antiferromagnetic ground state for undoped FeGa$_3$ [18] introduces new questions about the role of strong electronic correlations. In this paper we revisit several aspects of the electronic structure of electron and hole-doped FeGa$_3$, comparing results from the LDA and LDA + $U$ functional forms. Because in several cases the value of the gap is of some importance, in the appendix we indicate how the modified Becke-Johnson potential (see within) shifts bands and in some cases modifies magnetic moments giving better agreement with the experimental results.

II. STRUCTURE

FeGa$_3$ crystallizes in the tetragonal space group P4$_2$/mnm. Its lattice constants are $a = 6.2628$ Å and $c = 6.5546$ Å with four formula units (two Fe$_2$ dimers) per unit cell. Fe atoms are at $(0.3437, 0.3437, 0)$ and form dimer pairs in the $z = 0$ plane along $(110)$ and in $z = 1/2$ along the $(110)$ directions, as illustrated in Fig. 1. There are two inequivalent Ga sites: higher symmetry Ga1 at $(0, 0.5, 0)$, and lower symmetry Ga2 at $(0.1556, 0.1556, 0.262)$. Each Fe atom has eight Ga neighbors, two Ga1 at distances of 2.36 Å, and six Ga2, two of them at
2.39 and four at 2.48 Å (see Fig. 1). The paired Fe atoms are separated by 2.77 Å, a 12% larger distance than that between Fe atoms in bcc Fe metal (2.48 Å).

III. COMPUTATIONAL METHODS

The electronic structure calculations were performed with the WIEN2K code [21,22], based on density functional theory (DFT) utilizing the augmented plane wave plus local orbitals method (APW +lo) [23]. The calculations were well converged with respect to k mesh and R_{mK}K_{max}, using up to 1000 k points (10 × 10 × 9 mesh) and R_{mK}K_{max} = 7.0 cutoff. Selected sphere radii (a.u.) were the following: 2.27 for Fe, 2.16 for Ga, 2.35 for Mn and Co, 2.16 for Ge, and 2.22 for Zn.

Because the description of the electronic structure is in question, an assortment of exchange-correlation potentials have been used: LDA [16], LDA + U (LDA plus the on-site repulsion U within the fully localized limit functional) [24], and the Tran-Blaha modified Becke Johnson (from hereon mBJ) for augmented plane wave methods based on the procedure of Anisimov and Gunnarsson [26]. In this method the occupation of a target orbital (in this case the 3d Fe) is enforced. Due to the ambiguity in the charge state of Fe for FeGa3 using the approach proposed by Madsen and the WIEN2K code [21,22], based on density functional theory mechanisms and computational schemes studied, the magnetic Fe atoms in bcc Fe metal (2.48 Å), separated by 2.77 Å, a 12% larger distance than that between Fe-Ga sites, were presumed, with resulting effective magnetic moments in the unit cell (M_{tot}, in μ_B), and band gap (in eV) for the magnetic ground state of undoped and hole/electron doped FeGa3 within LDA, LDA + U (U = 3 eV, J = 0.8 eV), and mBJ.

### TABLE I. Fe/Mn/Co atomic moment (M, in μ_B), total magnetic moment in the unit cell (M_{tot}, in μ_B), and band gap (in eV) for the magnetic ground state of undoped and hole/electron doped FeGa3 within LDA, LDA + U (U = 3 eV, J = 0.8 eV), and mBJ.

<table>
<thead>
<tr>
<th>FeGa3</th>
<th>M Fe1/Fe2</th>
<th>M Fe3/Fe4</th>
<th>M_{tot}</th>
<th>Gap</th>
</tr>
</thead>
<tbody>
<tr>
<td>LDA</td>
<td>0.00/0.00</td>
<td>0.00/0.00</td>
<td>0</td>
<td>0.52</td>
</tr>
<tr>
<td>LDA + U</td>
<td>1.07/−1.07</td>
<td>1.07/−1.07</td>
<td>0</td>
<td>0.47</td>
</tr>
<tr>
<td>mBJ</td>
<td>0.00/0.00</td>
<td>0.00/0.00</td>
<td>0</td>
<td>0.57</td>
</tr>
<tr>
<td>FeGa2.75Zn0.25</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>LDA</td>
<td>0.40/0.40</td>
<td>0.00/0.00</td>
<td>0.8</td>
<td>0</td>
</tr>
<tr>
<td>mBJ</td>
<td>1.00/1.00</td>
<td>−0.50/−0.50</td>
<td>1.0</td>
<td>0.04</td>
</tr>
<tr>
<td>FeGa2.5Zn0.5</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>LDA</td>
<td>0.75/0.75</td>
<td>0.07/0.34</td>
<td>1.9</td>
<td>0</td>
</tr>
<tr>
<td>mBJ</td>
<td>1.29/1.29</td>
<td>0.77/−0.95</td>
<td>2.0</td>
<td>0.14</td>
</tr>
<tr>
<td>FeGa2.5Ge0.25</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>LDA</td>
<td>0.22/0.22</td>
<td>0.23/0.23</td>
<td>0.9</td>
<td>0</td>
</tr>
<tr>
<td>mBJ</td>
<td>0.42/0.42</td>
<td>0.20/0.20</td>
<td>1.0</td>
<td>0</td>
</tr>
<tr>
<td>FeGa2.5Ge0.5</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>LDA</td>
<td>0.43/0.36</td>
<td>0.40/0.40</td>
<td>1.7</td>
<td>0</td>
</tr>
<tr>
<td>mBJ</td>
<td>0.52/0.52</td>
<td>0.23/0.23</td>
<td>1.0</td>
<td>0</td>
</tr>
</tbody>
</table>

(see Table I). This result is consistent with the observed diamagnetism in pure FeGa3 and with previous electronic structure calculations [18,19]. In Fig. 2 the band structure with band character plot and DOS of FeGa3 within LDA are shown.

**Flats**

**Antiflats**

IV. STOICHIOMETRIC FeGa3

LDA. Both ferromagnetic and antiferromagnetic orientations within the Fe2 dimers have been studied. Within LDA (GGA) only a nonmagnetic state can be stabilized (see Table I). This result is consistent with the observed diamagnetism in pure FeGa3 and with previous electronic structure calculations [18,19]. In Fig. 2 the band structure with band character plot and DOS of FeGa3 within LDA are shown. The electronic state is insulating with a band gap of 0.52 eV.

Flat bands both below and above the gap give rise to a large DOS into which electrons or holes will be doped. Most of the contribution to states around the Fermi level comes from narrow Fe-d bands with little Ga-p contribution. For Fe 3d states we use a local coordinate system with the local z axis oriented along the dimer axis (as shown in Fig. 1). Using this local coordinate system the DOS looks as shown in the right panel of Fig. 2 with seemingly pseudocubic dz^2, dxz, dyz occupation. Below the gap, occupied dz^2, dxz, dyz bands form a narrow, 0.35 eV wide four-band/spin complex. Above the gap, dz^2 and dxz bands form a 0.4 eV wide two-band/spin complex. This different orbital character had been pointed out earlier by Singh [18] and by Yin and Pickett [19].

**LDA + U.** For the undoped compound, when an onsite Coulomb repulsion is included, a magnetic state can only be obtained for an AFM ordering within the dimers at low U (the magnetic moments vanish when a FM order is set). The magnitude of the magnetic moment increases gradually as the U value does (from 0.5 μ_B for U = 2 eV, to 1.07 μ_B for U = 3 eV, and 1.63 μ_B for U = 4 eV). The derived magnetic moments are in agreement with those obtained by Yin et al. [18]. An insulating state is retained for U in the
FIG. 2. (Color online) Left panel: band structure with band character plot (Fe highlighted) of nonmagnetic FeGa$_3$ within LDA, illustrating the predicted band gap that is in agreement with experiment. Right panel: orbital resolved DOS for Fe orbitals, in local coordinates (see text and Fig. 1) for nonmagnetic FeGa$_3$ obtained within LDA. The Fermi level is at zero.

2–4 eV range, but surprisingly the band gap closes as $U$ increases. The antiferromagnetic spin singlet scenario derived from LDA + $U$ calculations at $U = 3$ eV gives the same band gap as the LDA result (with the DOSs differing only in some specifics) and is consistent with transport and thermodynamic experiments (see Table I).

A. Analysis of band character

In halides, oxides, and some chalcogenides of iron, it is possible and very useful to identify the charge state (also known as formal valence) of Fe. This underlying picture provides substantial guidelines on the character of excitations that are likely to dominate the low energy behavior of the system. In some unusual (semi)metallic transition metal compounds, viz. CoSb$_3$ [29], such identification proves to be difficult, with unconventional pictures arising. We preface our study of doping of FeGa$_3$ with information relating to the Fe charge state (also called formal valence). We remind that the formal charge state often has only a very indirect connection to the physical charge density of atoms in the compound [30].

The integrated partial DOS, obtained from projections of the Bloch states, provides a guideline for the 3$d$ occupation of Fe. Supposing that true 3$d$ character falls off above 1.5 eV, (i.e., higher lying $d$ character reflecting tails of Ga atoms extending into the Fe sphere), the $d_{x^2-y^2}$, $d_{xy}$, $d_{xz}$ orbitals are fully occupied, 6 e$^-$/Fe. The other two orbitals, local $d_{3z^2}$ and $d_{4z^2}$ (which are very distinct orientationally and probably chemically), are 75% occupied, thus providing 3 e$^-$/Fe. The inferred occupation is then a surprising Fe$^{+1.4}$ (Ga$_6$)$^{+2}$. Although this characterization is not outrageous—Ga is quite electropositive and easily donates electrons to neighboring electronegative atoms, this picture should be given further scrutiny.

B. Fe-Fe dimer from Wannier function perspective

There are, incontrovertibly, 17 occupied bands per spin channel per Fe$_2$ dimer cluster. This situation, and especially the gap obtained even in the weakly correlated treatment, strongly suggests covalent (or metallic) bonding rather than ionic bonding as in many Fe insulators. Since the starting procedure is to assign orbitals localized at specific sites in the initial projection to obtain Wannier functions (WFs) [31,32], our choice was to have (per spin) four electrons per Fe, two electrons for six of the Ga atoms and one electron for the other six Ga atoms. Often in complex structured materials these initial associations do not persist, and that was the case here. The agreement between the occupied band structure obtained from Wannier function interpolation and that derived from the DFT calculation is excellent (see Fig. 3), indicating a faithful (though not unique) transformation to WFs. Four different initial projections resulted in four sets of WFs with the same total spread (mean localization). A persistent feature throughout the sets was that, of the 34 WFs/spin, precisely two are centered in the middle of dimers, i.e., one per dimer as can be seen in the top left panel of Fig. 4, or 1/2 electron per Fe. Most of the other 32 Wannier functions/spin resemble each other: lopsided objects with much of the occupation assignable to the Fe site (top right panel of Fig. 4). In some cases 1–3 $t_{2g}$-like WFs centered on the Fe result, and these have the lowest spread of any of the WFs (lower panel of Fig. 4).

The “dimer bonding WF” introduces a peculiar and, to our knowledge, unprecedented local orbital picture of an unpolarized metal-atom-based insulator, and is related directly to the dimer structure in the cell. It corresponds to a one-center

FIG. 3. (Color online) Comparison between the band structure obtained from the DFT calculation (in black) and the Wannier function interpolation (in red). The $k$ mesh used in the Wannier function calculation does not include $k$ points along some symmetry lines. Therefore, that the interpolated band structure from Wannier functions agrees with the Bloch bands provides a measure of the precision of the Wannier function transformation.

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occupied pseudocubic “\(t_2g\)” orbitals and empty “\(e_g\)” orbitals is a distinguishing feature of the Fe\(_2\) dimer, as is strong mixing with the Ga \(s\)-\(p\) orbitals.

**C. Charge density of flat near-gap bands**

Figure 5 shows 3D isosurfaces of the charge density for the narrow Fe \(3d\)-dominated bands below and above the gap. Consistent with the discussion provided above, the occupied states are a mixture of pseudocubic \(d_{z^2}\) and \(d_{x^2-y^2}\) orbitals (\(\gamma\) along the dimer axis), with a smaller contribution from \(d_{xy}\), and are roughly circular in cross section around the dimer axis. The unoccupied states are a combination of pseudocubic \(e_g\) states: \(d_z\) orbitals directed along the dimer axis, and \(d_{x^2-y^2}\) with lobes perpendicular to the dimer axis. This density is decidedly noncircular in cross section. Both densities reflect antibonding character, or at least nonbonding character, with no evidence of bonding charge. There is negligible contribution to the density that is displayed from Ga sites. The very small dispersion of the bands bordering the gap suggests rather localized molecular orbitals as the basic underlying feature for near-gap states.

**V. DOPED FeGa\(_3\)**

We have performed calculations in which both \(4\rho\) (Ga) and \(3d\) (Fe) substitutional doping mechanisms have been explored in the 12-atom cell described above: either one Ge or one Zn were substituted on Ga1 or Ga2 sites (doping level \(y = 0.25\), \(0.5\), respectively) and Fe was substituted by either one Co or one Mn (doping level \(x = 0.25\)). Within LDA our results are consistent with those presented by Singh within GGA [19]. Due to the steep and large DOS on either side of the gap, an itinerant FM state is obtained in all cases of low doping (Stoner mechanism for itinerant ferromagnetism). However, the magnetic state is different for the two types of directions (Stoner mechanism for itinerant ferromagnetism). However, the magnetic state is different for the two types of directions of doping, as we will describe below.

The scenario in which semiconducting FeGa\(_3\) has singlet Fe\(_2\) dimers (an antiferromagnetic state in a DFT-based calculation) was proposed by Yin and Pickett based on LDA + \(U\) calculations [18]. As mentioned above, for the stoichiometric compound, LDA and LDA + \(U (U = 3 \text{ eV})\) give very similar band gaps consistent with the experiment. When doping occurs, and especially when substitution is done on the Fe site, effects of correlation are likely to become more evident. We also pursue this goal in the present section.

Table I shows the magnetic moments for each of the atoms in the metal dimers, the total magnetic moment in the cell, and the band gap for each of the cases studied in the corresponding magnetic ground state. This table will guide much of the discussion that follows.

**A. Hole doping Fe \(\rightarrow\) Mn and Ga \(\rightarrow\) Zn within LDA**

Hole doping has been explored on the Fe site (replacing one Fe by Mn) and by substitution on the Ga site by Zn: Ga1 substitution corresponds to a doping level of \(y = 0.25\), and the Zn atom has a pair of Fe atoms at a distance of 2.36 \(\text{Å}\). Ga2 substitution corresponds to a doping level of \(y = 0.5\), and the substituted Zn also has a pair of Fe atoms at a distance of 2.50 \(\text{Å}\) and one of the Fe of the other dimer at 2.39 \(\text{Å}\) (see Fig. 1).
For hole (Mn) doping on the Fe site, for the lower $U$ value of 2 eV, only a FM ordering within the pairs can be obtained. A strong moment of $1.43 \mu_B$ on Mn ($S = \frac{5}{2}$) is obtained. The resulting electronic structure has the same features as that obtained within LDA: a HM FM state. Thus at $U = 2$ eV correlation effects do not appear to be significant.

For $U \geq 3$ eV the picture changes qualitatively. Not only can states with the magnetic moments being aligned and antialigned be obtained, but the AFM alignment becomes energetically favored. The lower panel of Fig. 6 shows the LDA $+$ $U$ ($U = 3$ eV) orbital resolved density of states of the Mn atom in Fe$_{0.75}$Mn$_{0.25}$Ga$_3$ for the energetically favored AFM alignment within the dimers. The magnetic moments are strengthened with $U$ (see Table I). While HM character remains, the onsite Coulomb repulsion shifts certain $d$ bands by more than 1 eV giving rise to distinctive changes in configuration. A band with $d_{z^2}$ character appears within the gap in the minority spin channel, in contrast to the LDA case. The complete $d_{z^2}$ spectral density within the gap strongly implies that for an isolated Mn dopant (i.e., the low doping limit) an unoccupied $d_{x^2-y^2}$ gap state will appear, perhaps near mid-gap, when strong correlations are considered. The band shifts are even more noticeable for higher $U$ values, with the majority gap closing accompanied by an increase in the magnetic moments of Mn and Fe that reach values of $3.00 \mu_B$ and $2.05 \mu_B$, respectively, and a widening of the bands around the Fermi level.

In both cases, only an itinerant FM state can be obtained within LDA. A half metallic (HM) FM state is obtained for Fe$_{0.75}$Mn$_{0.25}$Ga$_3$ with magnetic moments of 0.76 $\mu_B$ on the Mn atom, 0.26 $\mu_B$ on the paired Fe, and the other Fe$_2$ dimer remaining nonmagnetic (see Table I). The corresponding density of states is shown in the upper panel of Fig. 6. It exhibits a simple exchange splitting plus rigid-band behavior characteristic of an itinerant FM. The single hole difference leaves $E_F$ lying within the four $3d$ bands of the metallic minority spin channel, which are very strongly Mn character—the hole remains on the Mn atom. Magnetism arises from the $t_{2g}$ orbitals, with larger contribution from the $d_{yz}$ orbital at the Fermi level. The exchange splitting is about 0.25 eV.

For FeGa$_{2.5}$Zn$_{0.5}$Co$_{0.25}$ an itinerant FM state emerges with magnetism arising also from the $d_{yz}$ orbital. The hole is localized on the Fe atoms closer to the substituted Zn (see Table I always showing higher magnetic moments on the Fe atoms closer to the Zn, with the other Fe atoms having a significantly lower magnetic moment or even being nonmagnetic).

Experimental data on Mn- and Zn-doped FeGa$_3$ differ from the LDA-based predictions of emergence of a conducting FM state. $p$-type doping shifts the Fermi level into the valence band and gives rise to metallic behavior, whereas transport measurements for hole doped FeGa$_3$ show no insulator-metal transition but instead semiconducting behavior, not consistent with itinerant behavior.

B. Hole doping Fe $\rightarrow$ Mn within LDA $+ U$

For hole (Mn) doping on the Fe site, for the lower $U$ value of 2 eV, only a FM ordering within the pairs can be obtained. A strong moment of $1.43 \mu_B$ on Mn ($S = \frac{5}{2}$) is obtained. The resulting electronic structure has the same features as that obtained within LDA: a HM FM state. Thus at $U = 2$ eV correlation effects do not appear to be significant.

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C. Electron doping Fe $\rightarrow$ Co and Ga $\rightarrow$ Ge within LDA

Electron doping at the Fe site (by Co) and at the Ga site (by Ge) also gives rise to an itinerant FM state within LDA. In this case, magnetism arises from the $e_g$-like orbitals and the total moment of $1 \mu_B$ is spread rather equally across all transition metal ions—the electron is less localized (see Table I). There are only small differences in the DOS for electron doping on the Fe or Ga site: Low level electron doping with Co for Fe gives a simple rigid band shift downward of the majority spin channel; when doping with Ge different splittings appear for $d_{z^2}$, $d_{xy}$ orbitals due to the change in local environment with respect to the Co-doped compound (compare top panel of Fig. 7 for Fe$_{0.75}$Co$_{0.25}$Ga$_3$ with Fig. 8 for FeGa$_{0.5}$Ge$_{0.5}$).

From experiments, Co-doped FeGa$_3$ behaves differently from the Ge-doped counterpart. The Ge-doped compound is ferromagnetic with a positive Curie-Weiss temperature whereas experiments for Co doping show an AFM ordering at low T. DFT-based calculations do not account for that difference, always favoring a ferromagnetic alignment of moments. The main difference with respect to hole doping is the more delocalized picture with the moments being equally distributed among all the metal atoms, in contrast to hole doped FeGa$_3$ where there is a greater localization of the magnetic moments.

D. Electron doping Fe $\rightarrow$ Co within LDA $+ U$

For the lower $U$ value of 2 eV correlation effects are not significant in electron doped FeGa$_3$; a HM FM state is derived. At $U = 3$ eV a ground state with antialigned
FIG. 7. (Color online) Orbital resolved DOS of Co atoms in local coordinates in the magnetic ground state of $\text{Fe}_{0.75}\text{Co}_{0.25}\text{Ga}_3$ within LDA (upper panel) and LDA + $U$ (lower panel). Electron doping primarily drives the Fermi level into the conduction band giving rise to a half metallic state upon doping. Positive/negative values of the DOS correspond to the spin-up/spin-down channel. The Fermi level is set at zero.

FIG. 8. (Color online) Orbital resolved DOS of the nonequivalent Fe atoms in local coordinates in the magnetic ground state of $\text{FeGa}_2$.5$\text{Ge}_0$.5 obtained within LDA. The upper two panels show the DOS of Fe1 and Fe2 with partially occupied $d_{z^2}$ and $d_{x^2-y^2}$ orbitals. The lower panel shows the DOS at Fe3/Fe4 sites. Electron doping through Ge substitution pushes the Fermi level into the conduction band for both spin channels and induces magnetic moments on Fe supported by exchange splitting. Positive/negative values of the DOS correspond to the spin-up/spin-down channel. The Fermi level is set at zero.

moments is obtained. The lower panel of Fig. 7 shows the orbital resolved DOS of the Co atom in $\text{Fe}_{0.75}\text{Co}_{0.25}\text{Ga}_3$ for the LDA + $U$ ($U = 3$ eV) state. The picture upon electron doping appears somewhat simpler than for hole doping: The various orbital projected densities of states can be visualized as being connected adiabatically to their $U = 0$ position (upper panel) with a HM state persisting. The outstanding difference is that the occupied $d_{z^2} + d_{x^2-y^2}$ weight above the gap converts to predominantly $d_{z^2}$. This change corresponds to Co introducing an occupied $d_{z^2}$ majority gap state into the gap at low doping. The Co ion remains low spin, whereas the magnetic moment on Fe strengthens upon introducing $U$ (see Table I). For $U \geq 4$ eV noticeable shifts in the $d$ bands take place, with the Fe moment increasing up to 2.05 $\mu_B$ for $U = 5$ eV while Co remains in its low spin state, with induced moment of 0.2 $\mu_B$ irrespective of the $U$ value over the range we studied.

VI. DISCUSSION

As mentioned above, there is no unambiguous picture about the presence/absence of magnetism and/or correlations in $\text{FeGa}_3$. In agreement with previous works, the observed gap for undoped $\text{FeGa}_3$ (formed between $t_{2g}$ pseudocubic states at the top of the valence band and $e_g$ states at the bottom of the conduction band) can be reproduced without the inclusion of magnetism and correlations. This analysis is consistent with susceptibility measurements that indicate a diamagnetic state below RT [1] that is also supported by the absence of local moments in Fe Mössbauer spectra [5].

The antiferromagnetic spin singlet scenario derived from LDA + $U$ calculations ($U = 3$ eV) is consistent with transport and thermodynamic experiments, combined with neutron powder diffraction data, interpreted as showing that $\text{FeGa}_3$ is a correlated band insulator with a complex antiferromagnetic ordering [15]. Photoemission experiments agree with the correlated picture since the observed band dispersions are well reproduced by calculations within the LDA + $U$ scheme ($U = 3$ eV) [34]. The presence of magnetism in undoped $\text{FeGa}_3$ is also consistent with muon spin rotation studies that show a spin polaron band that requires the existence of Fe moments [6].

Electron or hole doping described without including correlations gives rise to an itinerant FM state (Stoner magnetism) without preformed moments in the undoped compound. This type of result is consistent with experiments that show that $\text{FeGa}_{3-x}\text{Ge}_x$ is a weak itinerant ferromagnet but is difficult to reconcile with the role of strong correlations in the FM instability found beyond $y_c = 0.13$ [13].

This calculated metallic FM state also contrasts with experiments in Co-doped $\text{FeGa}_3$ that show itinerant antiferromagnetic behavior and suggest the existence of in-gap states at low doping [12]. The correlated picture shows that Co substitution for Fe introduces a localized electronic gap state and gives rise to antialigned moments within the dimers, very different from the uncorrelated picture and supporting the experiments.

Experimental data on Mn and Zn doping also differ from the LDA-based predictions of emergence of a HM FM state. Gamza et al. [15] showed that hole doping does not give rise to an insulator-to-metal transition. They found instead
that both substitution of Zn onto the Ga site, or Mn on the Fe site introduces states into the semiconducting gap that remain localized, suggesting the formation of small magnetic polarons. Using neutron powder diffraction measurements and DMFT, they establish that the complex magnetic order for FeGa₃ above room temperature is almost unaffected by hole doping even though dynamical correlation effects become stronger. Some of these observations are again in better agreement with the correlated picture that suggests that Mn doping produces an in-gap hole state and an AFM alignment within the dimers (even though the calculated state within LDA + U is HM).

VII. SUMMARY

To summarize, density functional theory methods have been applied to follow the evolution of the magnetic and electronic properties of FeGa₃ with doping, where experiment shows that complex behavior including magnetism and quantum critical behavior arises. A specific interest here is to probe the difference for both electron and hole doping when doping is done on the magnetic Fe (dimer) site or on the surely uncorrelated Ga site. Doping on either site introduces gap states or moves the chemical potential into bands on either side of the gap.

Using conventional DFT for weakly correlated materials, the behavior upon substitution on the Fe site (disturbing the dimers) or on the Ga site (doping off the dimers) is similar: an itinerant ferromagnetic state emerges, as might be anticipated with this approach. However, there are clear differences between electron and hole doping: Whereas electron doping gives rise to a more itinerant and delocalized picture (with magnetic moments evenly distributed for all the Fe atoms in the unit cell), upon hole doping there is a higher degree of localization of the magnetic moments—moments develop on the dimer closest to the dopant atom. Evidently the response to doping of states below the gap is quite different from that of states above the gap.

When applying the correlated LDA + U method, hole doping is also quite different from electron doping. Co always remains its low spin state, while Mn is strongly magnetic. Whether this difference reflects changes in the host states above and below the gap, or is due more to differences between Mn and Co, remains unclear. Strong correlation effects lead to interdimer effects: Doping on one dimer induces strong moments on the other (“undisturbed”) Fe₂ dimer. Correlation effects are needed to be able to reconcile theoretical predictions with some of the rich behavior observed in doped FeGa₃. Understanding the interplay between localized and itinerant magnetism (including in-gap states at low doping) will be crucial to explain the peculiar puzzles posed by this intermetallic compound.

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For both doping levels the gap opening is again possible due to the splitting of the d$_{yz}$-like orbital for the minority spin channel of Fe atoms, being shifted above the Fermi level.

As commonly found in other applications, mBJ tends to increase the values of the magnetic moments (Table I) [28]. The shifts in the band structure and the increase in the magnetic moments with respect to LDA are consistent with changes in the charge inside the atomic spheres: increased for Fe and accordingly reduced for Ga atoms.